

NPN 2N2222 - 2N2222A PNP 2N2907 - 2N2907A

SILICON PLANAR EPITAXIAL TRANSISTORS

The 2N2222 and 2N2222A are NPN transistors mounted in TO-18 metal package with the collector connected to the case .

They are primarily intended for high speed switching. The 2N2222 is also suitable for d.c. and v.h.f./u.h.f. amplifiers .

PNP complements are 2N2907 and 2N2907A . Compliance to RoHS

ABSOLUTE MAXIMUM RATINGS

Symbol	R	Ratings			Unit	
V _{CEO}	Collector-Emitter Voltage		2N2222A	40(1)	V	
▼ CEO	Collector-Emitter voltage		2N2222	30	V	
V	Collector Page Voltage		2N2222A	75	\/	
V _{CBO}	Collector-Base Voltage		2N2222	60	V	
V	Emitter Base Voltage		2N2222A	6	V	
V _{EBO}	Emitter-Base Voltage		2N2222	5	V	
Ic	Collector Current		2N2222A	800	mA	
IC .	Collector Current		2N2222	000	ША	
P _D	Total Power Dissipation	Dissipation $ (0) _{} = 25^{\circ} _{}$	2N2222A	0.5	Watts	
	Total Forest Biodipation	C Tarrib 20	2N2222	0.0	vvallo	
P _D	Total Power Dissipation	@ T _{case} = 25°	2N2222A	1.2	Watts	
- 0	Total Tower Blodipation		2N2222			
T _J	Junction Temperature		2N2222A	200	°C	
· J	ouncion i emperatare		2N2222	250	<u> </u>	
T-	Storage Temperature range		2N2222A	-65 to +200	°C	
T _{Stg}			2N2222	-03 10 +200	C	

⁽¹⁾ Applicable up to $I_C = 500 \text{mA}$

THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit	
R _{thJ-a}	Thermal Resistance, Junction to ambient in free air	2N2222A 2N2222	350	K/W
R _{thJ-c}	Thermal Resistance, Junction to case	2N2222A 2N2222	146	K/W



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ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)		Min	Тур	Mx	Unit
I _{CBO}	Collector Cutoff Current	V _{CB} =60 V, I _E =0V V _{CB} =50 V, I _E =0V	2N2222A 2N2222	-	-	10	nA
I _{CBO}	Collector Cutoff Current	V _{CB} =60 V, I _E =0V, T _j =150°C V _{CB} =50 V, I _E =0V, T _j =150°C	2N2222A 2N2222	-	-	10	μΑ
I _{EBO}	Emitter Cutoff Current	V _{BE} =3.0 V, I _C =0	2N2222A 2N2222	-	-	10	nA
I _{CEX}	Collector Cutoff Current	V _{CE} =60 V, -V _{BE} =3V	2N2222A 2N2222	-	-	10	nA
V _{CEO}	Collector Emitter Breakdown Voltage	I _C =10 mA, I _B =0	2N2222A 2N2222	40 30	-	-	V
V _{CBO}	Collector Base Breakdown Voltage	I _C =10 μA, I _E =0	2N2222A 2N2222	75 60	-	-	V
V _{EBO}	Emitter Base Breakdown Voltage	I _E =10 μA, I _C =0	2N2222A 2N2222	6	-	-	V
h _{FE}	DC Current Gain	I _C =0.1 mA, V _{CE} =10 V	2N2222A 2N2222	35	-	-	
		I _C =1 mA, V _{CE} =10 V	2N2222A 2N2222	50	-	-	
		I_{C} =10 mA, V_{CE} =10 V	2N2222A 2N2222	75	-	-	
		I_C =10 mA, V_{CE} =10 V T_{amb} = -55°	2N2222A 2N2222	35 -	-	-	-
		I _C =150 mA, V _{CE} =1 V (1)	2N2222A 2N2222	50	-	-	
		I _C =150 mA, V _{CE} =10 V (1)	2N2222A 2N2222	100	-	-	
		I _C =500 mA, V _{CE} =10 V (1)	2N2222A 2N2222	40 30	-	-	
V _{CE(SAT)}	Collector-Emitter saturation Voltage (1)	I _C =150 mA, I _B =15 mA	2N2222A 2N22222	- -	-	0.3	
		I _C =500 mA, I _B =50 mA	2N2222A 2N2222	- - -	-	1.6	\ /
V	Base-Emitter saturation	I _C =150 mA, I _B =15 mA	2N2222A 2N2222	-	-	1.2 1.3	V
V _{BE(SAT)}	Voltage (1)	I _C =500 mA, I _B =50 mA	2N2222A 2N2222	-	-	2.6	

Symbol	Ratings	Test Condition(s)		Min	Тур	Mx	Unit
£	Transition fraguency	I _C =20 mA, V _{CE} =20 V	2N2222A	250	-	-	MHz
די	Transition frequency	f= 100MHz	2N2222	300	-	-	IVIITZ
h	Small signal current gain	I _C =1 A, V _{CE} =2.0 V	2N2222A	3	-	-	
n _{fe}		1C= 1 A, VCE=2.0 V 2N2222	2N2222	2.5	-	-] -



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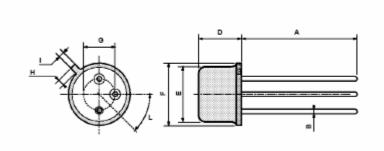
Symbol	Ratings	Test Condition(s)		Min	Тур	Mx	Unit
t _d	Delay time	I _C =150 mA ,I _B =15 mA	2N2222A	-	-	10	20
t _r	Rise time	-V _{BE} =0.5 V	2N2222A	-	-	25	ns
Cc	Collector capacitance	$I_{E}=I_{e}=0 ,V_{CB}=10 V$ f = 100kHz	2N2222A 2N2222	-	-	8	pF
CE	Emitter capacitance	$I_{C}=I_{c}=0 ,V_{EB}=0.5 V$ f = 100kHz	2N2222A 2N2222	-	-	25 -	pF
r _b ,C _C	Feedback time constant	I _C =20 mA, V _{CE} =20 V f= 31.8MHz	2N2222A 2N2222	-	-	150 -	ps

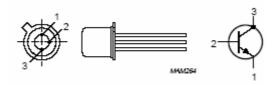
(1) Pulse conditions : tp < 300 μ s, δ =2%

MECHANICAL DATA CASE TO-18

	DIMENSIONS					
	mm	inches				
Α	12,7	0,5				
В	0,49	0,019				
D	5,3	0,208				
E	4,9	0,193				
F	5,8	0,228				
G	2,54	0,1				
Н	1,2	0,047				
I	1,16	0,045				
L	45°	45°				

Pin 1 :	Emitter
Pin 2 :	Base
Pin 3 :	Collector





Information furnished is believed to be accurate and reliable. However, CS assumes no responsability for the consequences of use of such information nor for errors that could appear.

Data are subject to change without notice.